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CLASS-E CURRENT-DRIVEN CENTER-TAPPED LOW dv/dt RECTIFIER

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Abstract – An analysis for a Class E current-driven center-tapped low dv/dt rectifier taking into account the transformer leakage inductances is given along with experimental verifications. The rectifier diodes turn on and off at low dw/dt. This results in low switching noise and low switching losses. Diode parasitic capacitances do not adversely affect the circuit operation. The absolute value of di/dt is limited at diode turn-off, reducing the reverse recovery current. The circuit is operated at a low output voltage ripple and, therefore, at a low power loss in the equivalent series resistance (ESR) of the filter capacitor. Experimental tests were performed for a rectifier circuit operated at an output power of $P_{O} = 60$ W, an minimum frequency of f = 500 kHz, and an output voltage of $V_{O} = 3.3$ V. The theoretical and the experimental results are in good agreement. Experimental measurements demonstrate that the rectifier is suitable for high-power density, high-frequency applications that requires low-output voltages and high-currents.

I. INTRODUCTION

The increasing demand for small-volume light-weight power supplies has necessitated the development of high-frequency high-efficiency power converter circuits. This can be achieved if switching losses are eliminated. In class E rectifiers [1]-[7], zero-voltage turn on of the diode is achieved. Moreover, the diodes turn on and off at low dv/dt resulting in low switching noise. Therefore, these rectifiers can be operated at high switching frequencies with a nearly constant efficiency over a wide load range [4]-[6]. In the class E current-driven center-tapped rectifier, the output voltage ripple is drastically reduced, the average current through each diode is one-half of the output current, and a lower volume transformer than in the class E full-wave rectifier [7] can be used. As a result, the class E current-driven center-tapped rectifier is suitable for high power-density applications at high-output currents, e.g., higher than 10 A and low-output voltages, e.g., 3.3 V or 5 V, which are the standard supply voltages of advanced VLSI circuits. Moreover, Class E rectifiers can be used in combination with class D and class E resonant inverters to build high-frequency dc-dc converters [8]-[21].

The purpose of this paper is to present an analysis and experimental results for a class E current-driven center-tapped low dv/dt rectifier. The rectifier was tested on a 60 W power supply operated at a line ac voltage ranging from 75 to 275 V_{rms} , an output current varying from 1.8 to 18 A, and an output voltage $V_Q = 3.3$ V regulated over the entire line voltage

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and load current ranges. The nominal operating frequency of the converter circuit was f = 500 kHz. A maximum efficiency $\eta = 80$ % was achieved for the entire power supply at the maximum load and an ac input voltage $V_{Irms} = 220$ V.

II. CIRCUIT DESCRIPTION

A schematic circuit of the class E current-driven center-tapped low dv/dt rectifier and its model are shown in Figs. 1(a) and (b), respectively.



Fig. 1. Class E current-driven center-tapped low dw/dt rectifier. a) Schematic circuit. b) Model of the rectifier.

The rectifier consists of two diodes D_1 and D_2 , two capacitors C_1 and C_2 , a single-pole low-pass output filter $C_f - R_L$, and a center-tapped transformer with a turns ratio *n*. Resistor R_L is the dc load resistance. The diode parasitic capacitances are absorbed into capacitances C_1 and C_2 connected in parallel with the diodes. The entire leakage flux of the transformer has been taken into account by means of two

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leakage inductances $L_{\ell l}$ and $L_{\ell 2}$ on the secondary side. L_m is the magnetizing inductance placed on the primary side of the transformer.

The transformer primary side is supplied by sinusoidal current source

$$i = I_m \sin \omega t \tag{1}$$

where I_m and $\omega = 2\pi f$ are the amplitude and the angular frequency of the current, respectively.

III. PRINCIPLE OF OPERATION

The rectifier circuit can be operated at an on duty cycle of each diode D ranging from 0 to 1 and goes through four topological configurations during one switching period T = 1/f. These topological modes are defined by the diode states as given in Table I.

TABLE I.

	D_1	D2
$0 < D \le 0.5$		
$\phi \leq \omega t < \phi + 2\pi D$	ON	OFF
$\phi + 2\pi D \le \omega t < \phi + \pi$	OFF	OFF
$\phi + \pi \le \omega t < \phi + \pi + 2\pi D$	OFF	ON
$\phi + \pi + 2\pi D \le \omega t < \phi + 2\pi$	OFF	OFF
$0.5 < D \le 1$		
$\phi \le \omega t < \phi + 2\pi D$	ON	OFF
$\phi + 2\pi D \le \omega t < \phi + \pi$	ON	ON
$\phi + \pi \le \omega t < \phi + \pi + 2\pi D$	OFF	ON
$\phi + \pi + 2\pi D \le \omega t < \phi + 2\pi$	ON	ON

The current and voltage waveforms for the rectifier operated at $0 \le D \le 0.5$ and $0.5 \le D \le 1$ are shown in Figs. 2(a) and (b), respectively.

A. Operation for $0 < D \le 0.5$

The first topological mode begins at $\omega t = \phi$, when voltage v_{D1} across diode D_1 reaches zero turning diode D_1 on. Actually, D_1 turns on when v_{D1} reaches the threshold voltage V_T , e.g., $V_T = 0.4$ V for Schottky diodes. During this time interval, current i_1 of the upper secondary winding flows through D_1 . Diode D_2 is off and its voltage waveform is shaped by the shunt capacitor C_2 , according to $i_{C2} = C_2 dv_{C2}/dt$. The first mode ends at $\omega t = \phi + 2\pi D$, when current i_{D1} reaches zero, turning D_1 off.

During the second topological mode both D_1 and D_2 are OFF. Current i_1 flows through capacitor C_1 , voltage $v_{D1} = v_{C1}$ is shaped according to $i_{C1} = C_1 dv_{C1} / dt$. Since the capacitor current is zero at the beginning of the second topological mode, the derivative of v_{D1} is also zero at $\omega t = \phi + 2\pi D$. After diode D_1 turn-off, voltage v_{D1} slowly decreases because i_{C1} is negative. Since i_{C2} is positive, voltage v_{D2} increases and reaches the diode threshold voltage at $\omega t = \phi + \pi$, turning diode D_2 on. This ends the second mode.

The third topological mode begins at $\omega t = \phi + \pi$, when

diode D_2 turns on and ends at $\omega t = \phi + \pi + 2\pi D$, when it turns off. During this time interval, the lower secondary winding current i_2 flows through diode D_2 . The waveform of the voltage across diode D_1 and capacitor C_1 is still shaped by the current through C_1 . Therefore, it decreases, reaches its minimum value V_{DM} when i_{C1} is zero, and then increases when i_{C1} is positive.

The fourth mode begins, when current i_{D2} reaches zero and diode D_2 turns off. As in the first topological mode, C_2 shapes the voltage waveform of D_2 . Therefore, voltage v_{D2} slowly decreases from zero because i_{C2} is zero at $\omega t = \phi + \pi + 2\pi D$. The current through capacitor C_1 is positive and, therefore, voltage v_{D1} increases. Diode D_1 turns on at $\omega t = \phi + 2\pi$, when v_{D1} reaches the threshold voltage. This ends the fourth topological mode and the switching period.

B. Operation for $0.5 \le D \le 1$

The first and the third topological modes are identical for the first and the third topological modes of the rectifier operated at $0 < D \le 0.5$. The second topological mode begins at $\omega t = \phi + \pi D$ when diode D_2 turns on and ends at $\omega t = \phi + 2\pi D$ when current i_1 decreases to zero turning off diode D_1 . The fourth topological modes begins at $\omega t = \phi + \pi + 2\pi D$ when diode D_1 turn on and ends at $\omega t = \phi + 2\pi \pi D$ when diode D_1 turn on and ends at $\omega t = \phi + 2\pi \pi W$ with the turn-off of diode D_2 . During these two intervals both diodes are ON, terminals W and Z of the two secondary windings are shorted, and currents through these windings are $i_1 = -i_2$. The amplitudes of these current do not rise to dangerous values because the transformer primary side is driven by a current source.

III. RECTIFIER CIRCUIT ANALYSIS

The analysis of the Class E rectifier of Fig. 1(a) begins with the following assumptions.

- 1) The rectifier circuit is symmetrical. Therefore, $C_1 = C_2 = C_p$, and $L_{\ell l} = L_{\ell 2} = L$.
- 2) The parasitic resistances of the core and the windings, and the transformer stray capacitances are neglected.
- 3) The diodes are ideal and identical, i.e., they have zero threshold voltage, zero on-resistance, infinite offresistance, and zero minority carrier charge lifetime in the case of the *pn* junction diode.
- 4) Filter capacitor C_f is large enough to neglect the output voltage ripple. For this reason, the parallel combination of C_f and R_I can be replaced by a dc voltage source.
- 5) The sinusoidal current source driving the primary side of the rectifier transformer is ideal.
- 6) The transformer has a turns ratio of n for each secondary. Moreover, the winding and core resistances and the stray capacitance of the transformer are ignored. The magnetizing inductance L_m is assumed to be large enough to carry only a dc current. Therefore, it can be considered as an open circuit for the ac component of the current.



Fig. 2. Current and voltage waveforms in a class E current-driven center-tapped low dv/dt rectifier. a) Operation at $0 \le D \le 0.5$. b) Operation at $0.5 \le D \le 1$.

The equivalent circuits of the rectifier are linear during each interval given in Table I. Therefore, the Laplace transform can be used to analyze the rectifier circuit. Moreover, the relationship between the currents through the three transformer windings is given by

$$i(t) = \frac{1}{n} [i_1(t) - i_2(t)].$$
⁽²⁾

Combinations of (1) and (2) with equations resulting from the analysis of the four equivalent circuits of the rectifiers during one switching period allows for the derivation of the current and voltage expressions. As an examples, the equations of currents i_1 and i_2 and voltages $v_{D1} = v_{C1}$ and $v_{D2} = v_{C2}$ for each topological mode of a rectifier operated at $0 < D \le 0.5$ are given below.

A. First Topological Mode: $\phi < \omega t \le \phi + 2\pi D$

$$i_{1} = nI_{m}\sin\omega t$$

$$+ \left\{ \cos\phi \left[\omega^{2}\sin(\omega t - \phi) - \frac{\omega\omega_{o}}{\sqrt{2}}\sin\left[\frac{\omega_{o}}{\sqrt{2}}\left(t - \frac{\phi}{\omega}\right)\right] \right] \right\}$$

$$+ \sin\phi \left[\omega^{2}\cos(\omega t - \phi) - \frac{\omega_{o}^{2}}{2}\cos\left[\frac{\omega_{o}}{\sqrt{2}}\left(t - \frac{\phi}{\omega}\right)\right] \right] \right\}$$

$$+ \frac{\left[i_{1}(\phi) + i_{2}(\phi)\right]}{2}\cos\left[\frac{\omega_{o}}{\sqrt{2}}\left(t - \frac{\phi}{\omega}\right)\right]$$

$$- \frac{\left[2Vo + v_{C1}(\phi) + v_{C2}(\phi)\right]}{\sqrt{2}\omega_{o}L}\sin\left[\frac{\omega_{o}}{\sqrt{2}}\left(t - \frac{\phi}{\omega}\right)\right]$$
(3)

$$i_{2} = \frac{nI_{m}}{\left(\omega_{o}^{2} - 2\omega^{2}\right)}$$

$$x \left\{ \cos\phi \left[\omega^{2} \sin(\omega t - \phi) - \frac{\omega\omega_{o}}{\sqrt{2}} \sin \left[\frac{\omega_{o}}{\sqrt{2}} \left(t - \frac{\phi}{\omega} \right) \right] \right] \right\}$$

$$+ \sin\phi \left[\omega^{2} \cos(\omega t - \phi) - \frac{\omega_{o}^{2}}{2} \cos \left[\frac{\omega_{o}}{\sqrt{2}} \left(t - \frac{\phi}{\omega} \right) \right] \right] \right\}$$

$$+ \frac{i_{1}(\phi) + i_{2}(\phi)}{2} \cos \left[\frac{\omega_{o}}{\sqrt{2}} \left(t - \frac{\phi}{\omega} \right) \right]$$

$$- \frac{2Vo + v_{C_{1}}(\phi) + v_{C_{2}}(\phi)}{\sqrt{2}\omega_{o}L} \sin \left[\frac{\omega_{o}}{\sqrt{2}} \left(t - \frac{\phi}{\omega} \right) \right]$$

$$(4)$$

$$v_{C1} = 0$$

$$(5)$$

$$v_{C2} = \frac{nI_m}{\left(\omega_o^2 - 2\,\omega^2\right)C}$$

$$x \left\{ -\omega\cos\phi \left[\cos(\omega t - \phi) - \cos\left(\frac{1}{\sqrt{2}}\left(\frac{\omega_o t}{\omega} - \phi\right)\right)\right] \right\}$$

$$+ \sin\phi \left[\omega\sin(\omega t - \phi) - \frac{\omega_o}{\sqrt{2}}\sin\left(\frac{1}{\sqrt{2}}\left(\frac{\omega_o t}{\omega} - \phi\right)\right)\right] \right\}$$

$$+ \frac{\left[i_1(\phi) + i_2(\phi)\right]}{2\omega_o C}\sin\left(\frac{1}{\sqrt{2}}\left(\frac{\omega_o t}{\omega} - \phi\right)\right)$$

$$+ \left[v_{C_1}(\phi) + v_{C_1}(\phi) + 2Vo\right] \left[\cos\left(\frac{1}{\sqrt{2}}\left(\frac{\omega_o t}{\omega} - \phi\right)\right) - 1\right]$$

$$+ v_{C_2}(\phi)$$
(6)

B. Second Topological Mode: $\phi + 2\pi D \leq \omega t \leq \phi + \pi$

$$i_{1} = n \frac{I_{m}}{2} \sin \omega t$$

$$+ \frac{1}{2} [i_{1} (\phi + 2\pi D) + i_{2} (\phi + 2\pi D)]$$

$$x \cos \left[\omega_{o} \left(t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right]$$

$$- \frac{\left[v_{C1} (\phi + 2\pi D) + v_{C2} (\phi + 2\pi D) + 2V_{o} \right]}{2\omega_{o} L}$$

$$x \sin \left[\omega_{o} \left(t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right]$$
(7)

$$i_{2} = -n \frac{I_{m}}{2} \sin \omega t$$

$$+ \frac{1}{2} [i_{1} (\phi + 2\pi D) + i_{2} (\phi + 2\pi D)]$$

$$x \cos \left[\omega_{o} \left(t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right]$$

$$- \frac{\left[v_{C1} (\phi + 2\pi D) + v_{C2} (\phi + 2\pi D) + 2V_{O} \right]}{2\omega_{o} L}$$

$$x \sin \left[\omega_{o} \left(t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right]$$
(8)

$$\begin{aligned} v_{C1} &= nI_{m} \frac{\cos\omega t - 1}{2\omega C} \\ &+ \frac{i_{1} (\phi + 2\pi D) + i_{2} (\phi + 2\pi D)}{2} \sin \left[\omega_{o} \left(t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right] \\ &+ \frac{v_{C1_{1}} (\phi + 2\pi D)}{2} \cos \left[\omega_{o} \left(t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right] \\ &+ \frac{v_{C1} (\phi + 2\pi D) + 2V_{O}}{2} \cos \left[\omega_{o} \left(t - \frac{\phi}{\omega} - \frac{2\pi D}{\omega} \right) \right] \\ &- \frac{v_{C1_{1}} (\phi + 2\pi D) + v_{C2} (\phi + 2\pi D) + 2V_{O}}{2} + v_{C1} (\phi + 2\pi D) \end{aligned}$$
(9)

C. Third Topological Mode: $\phi + \pi < \omega t \le \phi + \pi + 2\pi D$

$$i_{1} = -\frac{mI_{m}}{\omega_{o}^{2} - 2\omega^{2}}$$

$$\times \left\{ \cos(\phi + \pi)\omega^{2}\sin(\omega t - \phi - \pi) - \cos(\phi + \pi)\frac{\omega\omega_{o}}{\sqrt{2}}\sin\left[\frac{\omega_{o}}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] + \sin(\phi + \pi)\left[\omega^{2}\cos(\omega t - \phi - \pi) + \frac{\omega_{o}^{2}}{2}\cos\left[\frac{\omega_{o}}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right]\right]\right\}$$

$$+ \frac{i_{1}\left(\phi + \pi\right) + i_{2}\left(\phi + \pi\right)}{2}\cos\left[\frac{\omega_{o}}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right]$$

$$- \frac{2V_{O} + v_{C1}\left(\phi + \pi\right) + v_{C2}\left(\phi + \pi\right)}{\sqrt{2}\omega_{o}L}\sin\left[\frac{\omega_{o}}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right]$$
(10)

 $i_2 = nI_m sin \, \omega t$

$$v_{C1} = -\frac{nI_m}{C(\omega_o^2 - 2\omega^2)}$$

$$x \left\{ -\omega \cos(\phi + \pi) \cos(\omega t - \phi - \pi) + \omega \cos(\phi + \pi) \cos\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] + \sin(\phi + \pi) [\omega \sin(\omega t - \phi - \pi)] - \frac{\omega_o}{\sqrt{2}} \sin\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] \right\}$$

$$+ \frac{i_1(\phi + \pi) + i_2(\phi + \pi)}{2\omega_o C}$$

$$x \sin\left[\frac{\omega_o}{\sqrt{2}}\left(t - \frac{\phi}{\omega} - \frac{\pi}{\omega}\right)\right] + \left[v_{C1}(\phi + \pi) + v_{C2}(\phi + \pi) + 2Vo\right] - \left[v_{C1}(\phi + \pi) + v_{C1}(\phi + \pi)\right]$$
(13)

D. Fourth Topological Mode: $\phi + \pi + 2\pi D < \omega t \le \phi + 2\pi$

$$i_{1} = n \frac{I_{m}}{2} \sin \omega t$$

$$+ \frac{1}{2} [i_{1} (\phi + 2\pi D + \pi)] \cos \left[\omega_{o} \left(t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right]$$

$$+ \frac{1}{2} [i_{2} (\phi + 2\pi D + \pi)] \cos \left[\omega_{o} \left(t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right]$$

$$- \frac{v_{C1} (\phi + 2\pi D + \pi)}{(2\omega_{o} L)} \sin \left[\omega_{o} \left(t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right]$$

$$- \frac{v_{C2} (\phi + 2\pi D + \pi) + 2Vo}{2\omega_{o} L} \sin \left[\omega_{o} \left(t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right]$$
(14)

$$i_{2} = -n \frac{I_{m}}{2} \sin(\omega t) + \frac{1}{2} [i_{1} (\phi + 2\pi D + \pi)] \cos \left[\omega_{o} \left(t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] + \frac{1}{2} [i_{2} (\phi + 2\pi D + \pi)] \cos \left[\omega_{o} \left(t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] - \frac{v_{C1} (\phi + 2\pi D + \pi)}{2\omega_{o} L} \sin \left[\omega_{o} \left(t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] - \frac{v_{C2} (\phi + 2\pi D + \pi) + 2V_{O}}{2\omega_{o} L} \sin \left[\omega_{o} \left(t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right]$$
(15)

$$-\frac{nI_{m}}{\omega_{o}^{2}-2\omega^{2}}\left\{\cos(\phi+\pi)\omega^{2}\sin(\omega t-\phi-\pi)\right.-\cos(\phi+\pi)\frac{\omega\omega_{o}}{\sqrt{2}}\sin\left[\frac{\omega_{o}}{\sqrt{2}}\left(t-\frac{\phi}{\omega}-\frac{\pi}{\omega}\right)\right]++\sin(\phi+\pi)\left[\omega^{2}\cos(\omega t-\phi-\pi)\right]-\frac{\omega_{o}^{2}}{2}\cos\left[\frac{\omega_{o}}{\sqrt{2}}\left(t-\frac{\phi}{\omega}-\frac{\pi}{\omega}\right)\right]\right]\right\}+\frac{i_{1}(\phi+\pi)+i_{2}(\phi+\pi)}{2}\times\cos\left[\frac{\omega_{o}}{\sqrt{2}}\left(t-\frac{\phi}{\omega}-\frac{\pi}{\omega}\right)\right]-\frac{2V_{O}+v_{C1}(\phi+\pi)+v_{C2}(\phi+\pi)}{\sqrt{2}\omega_{o}L}$$

$$\times\sin\left[\frac{\omega_{o}}{\sqrt{2}}\left(t-\frac{\phi}{\omega}-\frac{\pi}{\omega}\right)\right]$$
(11)

$$v_{C2} = 0 \tag{12}$$

$$\begin{aligned} v_{C1} &= -nI_m \frac{\cos \omega t - 1}{2 \,\omega C} \\ &+ \frac{i_1 \left(\phi + 2 \pi D + \pi\right)}{2} \sin \left[\omega_o \left(t - \frac{\phi - 2 \pi D - \pi}{\omega} \right) \right] \\ &+ \frac{i_2 \left(\phi + 2 \pi D + \pi\right)}{2} \sin \left[\omega_o \left(t - \frac{\phi - 2 \pi D - \pi}{\omega} \right) \right] + \\ &+ \frac{v_{C1} \left(\phi + 2 \pi D + \pi\right)}{2} \cos \left[\omega_o \left(t - \frac{\phi - 2 \pi D - \pi}{\omega} \right) \right] \\ &+ \frac{v_{C2} \left(\phi + 2 \pi D + \pi\right)}{2} \cos \left[\omega_o \left(t - \frac{\phi - 2 \pi D - \pi}{\omega} \right) \right] \\ &+ \frac{v_{C2} \left(\phi + 2 \pi D + \pi\right)}{2} \cos \left[\omega_o \left(t - \frac{\phi - 2 \pi D - \pi}{\omega} \right) \right] \\ &+ Vo \cos \left[\omega_o \left(t - \frac{\phi - 2 \pi D - \pi}{\omega} \right) \right] + v_{C1} \left(\phi + 2 \pi D + \pi\right) \\ &- \frac{v_{C1} \left(\phi + 2 \pi D + \pi\right) + v_{C2} \left(\phi + 2 \pi D + \pi\right) + 2V_0}{2} \end{aligned}$$
(16)

$$\begin{aligned} v_{C2} &= nI_m \frac{\cos \omega t - 1}{2 \omega C} \\ &+ \frac{i_1 (\phi + 2\pi D + \pi)}{2} \sin \left[\omega_o \left(t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] \\ &+ \frac{i_2 (\phi + 2\pi D + \pi)}{2} \sin \left[\omega_o \left(t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] \\ &+ \frac{v_{C1} (\phi + 2\pi D + \pi)}{2} \left\{ \cos \left[\omega_o \left(t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] - 1 \right\} \\ &+ \frac{v_{C2} (\phi + 2\pi D + \pi)}{2} \left\{ \cos \left[\omega_o \left(t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] - 1 \right\} \\ &+ V_O \left\{ \cos \left[\omega_o \left(t - \frac{\phi - 2\pi D - \pi}{\omega} \right) \right] - 1 \right\} \\ &+ v_{C2} (\phi + 2\pi D + \pi) \end{aligned}$$
(17)

where $\omega_O = 1/\sqrt{LC}$.

Combination of (1) to (17) allows for the calculation of parameters such as ϕ , D, the dc output current I_O , the maximum current through each diode I_{DM} , and the maximum reverse voltage across each diode V_{DM} . Unfortunately, the expressions of these quantities cannot be derived in a closed form. For this reason, a computer program has been developed to calculate these parameters.

Fig. 3 shows a plot of D as a function of load resistance R_I for $f_o = 4.9$ MHz (resulting from L = 15 nH and $C_p = 70$ nF) and a constant output voltage normalized with respect to the transformer turns ratio $V_{O}/n = 0.275$ (it has been assumed that $V_0 = 3.3$ V and n = 12). The diode duty cycle decreases as the output current decreases. Therefore, the current through the diodes becomes more impulsive at light loads. Moreover, a small variation of D is needed to regulate the output voltage over a wide load range, e.g., duty cycle D decreases from 0.6 to 0.45 for a load resistance increasing from 0.14 Ω to 1.4 Ω .

Figs. 4 depicts a plot of the maximum current through the

transformer primary winding I_m of R_L at $f_O = 4.9$ MHz and $V_{O}/n = 0.27$. Current I_{m} increases from 0.5 A to 5 A as the dc output current I_O increases from 2.3 A to 23 A. Therefore, both the dc output current and the primary current range in the same relative interval, e.g., 1 to 10 or 10% to 100%.

Both I_m and D depend on ω_0 and V_0/n while the diode maximum current and voltage are independ of these parameters.







Fig. 5. Normalized maximum current I_{DM}/I_O as a function of duty cycle D.

Fig. 5 shows I_{DM} normalized with respect to I_O as a function of D. The maximum normalized current through the diodes decreases from 1.5 to 1.1 as D increases from 0.4 to 0.6. Since D is in the range of 0.45–0.6 for a load resistance decreasing from 1.4 to 0.14, the maximum current through the diodes increases from 3.45 to 25 A for a dc output current ranging from 2.3 to 23 A. This shows that the current through the diodes does not significantly exceeds the dc output current when the rectifier is operated at full load.

A plot of V_{DM} normalized with respect to V_O as a function of D is shown in Fig. 6. The maximum normalized reverse voltage across the rectifier diodes increases from 3.5 to 4.3 for D increasing from 0.45 to 0.6. For a rectifier operated at an output voltage $V_O = 3.3$ V and a load resistance in the range to 0.14 to 14 W, the maximum voltage across the diodes increases from 11.5 V at full load to 14.2 V at light load. Because of the low values of V_{DM} , Schottky diodes can be used in the rectifier circuits. This allows for a high-frequency operation of the rectifier.



Fig. 5. Normalized maximum diode reverse voltage V_{DM}/V_O as a function of duty cycle D.

IV. DESIGN EXAMPLE AND EXPERIMENTAL RESULTS

A a full-range off-line power supply based on class DE dc-dc converter with a class D series resonant inverter and a class E current-driven center-tapped low dv/dt rectifier was built to operate at an input dc voltage $V_I = 120$ to 370 V_{dc}, a regulated output voltage $V_0 = 3.3$ V, an output power $P_0 = 60$ W, and a nominal operating frequency f = 500 kHz. The maximum output current of the converter was $I_{OM} = 18$ A, which corresponds to a minimum load resistance $R_{Lmin} = 0.18 \Omega$. The converter circuit was designed for the minimum input voltage and maximum load operation. The dc-to-dc voltage transfer function of the entire converter was $M_{max} = V_0 / V_{Imin} = 3.3 / 120 = 0.0275$. A class D series resonant inverter operated at a voltage transfer function $M_{Imax} = 0.383$ was used as a sinusoidal current source. Therefore, the rectifier voltage transfer function was $M_R = M_{max} / M_{Imax} = 0.0275 / 0.383 = 0.072$. As a result, the amplitude of the fundamental component of the primary winding voltage in phase with the primary current was calculated as $V_{Rm} = \sqrt{2} V_0 / M_R = 64.8$ V and the transformer turns ratio was n = 12.

The center-tapped transformer was built on a EFD30 Siemens N49 ferrite core. The primary was wound with 24 turns of AWG22 solid copper wire and the two secondary windings with 2 turns of copper strips 15×0.15 mm each. The measured transformer magnetizing inductance was $L_m = 1.23$ mH, the equivalent series resistance (ESR) of the three windings seen across the terminals of the primary winding was $R_S = 0.63 \Omega$, f = 500 kHz and each secondary leakage inductance was L = 18 nH. Two International Rectifier 32CTQ30 Schottky diodes were used in the rectifier. An external capacitance $C_P = 66$ nF was connected in parallel with each diode. Two electrolytic Oscon 100 μ F / 20 V capacitors connected in parallel were used as filter capacitors. Fig. 6 shows experimental voltage and current waveforms of the transformer primary winding at $V_I = 110$ V and f = 465 kHz. Fig. 7 shows the experimental waveforms of the voltages across diodes D_I and D_2 . The measured efficiency of the ac-dc converter including the front-end full-bridge transformerless rectifier is plotted in Fig. 8 as a function of I_O . The measured efficiency at the full load operation at a low line voltage $V_{Irms} = 120$ V was $\eta = 81$ % and was 1.5% higher than the efficiency measured at $V_{Irms} = 220$ V over the entire load range.



Fig. 6. Waveforms of voltage and current for the primary winding for the transformer at an operating frequency f = 465 kHz, ac input voltage $V_{Irms} = 110$ V, output voltage $V_O = 3.3$ V, and $R_L = 0.18 \Omega$. Vertical: 100 V/div. for v_p and 2 A/div. for *i*; horizontal 500 ns/div.



Fig. 7. Waveforms of the reverse voltage on each diode at an operating frequency f = 465 kHz, ac input voltage $V_{Irms} = 110$ V, output voltage $V_O = 3.3$ V, and $R_I = 0.18$ Ω . Vertical: 10 V/div.; horizontal 500 ns/div.



Fig. 8. Efficiency of the entire power supply versus output current at an ac input voltage $V_{Irms} = 220$ V and $V_o = 3.3$ V.

V. CONCLUSIONS

The analysis, design procedure, and experimental verification of a class E current-driven center-tapped low dv/dt rectifier have been presented. The leakage inductances of the transformer have been taken into account. In the class E rectifier, each diode turns on and of at zero voltage with a limited dv/dt at the turn-off and dv/dt = 0 at the turn-on. Moreover, di/dt is limited at the diode turn-off and a soft-reverse recovery of diodes is achieved. The class E current-driven center-tapped low dv/dt rectifier has been used to build a 60 W power supply operated at a line voltage varying from 85 to 260 V_{rms} and a regulated output voltage $V_O = 3.3$ V. A maximum efficiency $\eta = 80$ % has been achieved for the whole power supply at the maximum output current $I_O = 18$ A and input ac voltage $V_{Irms} = 220$ V.

Since zero-voltage turn-on of the switches is achieved, the rectifier efficiency can be increased if diodes are replaced by low on-resistance power MOSFETs. Theoretical analysis and experimental verifications of the class E current-driven center-tapped synchronous rectifier are recommended for future work.

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